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L Numser	Hits	Search Text	DB	Time stamp
3	1385	(P\$2substrat\$3 ("P" adj3 tupe adj2	USPAT;	2001/08/03 17:00
4	17824	substrate)) (P\$2source ("P" adj7 source))	US-PGPUB USPAT;	2001/08/03 17:00
5	38650	gate adj3 electrode	US-PGPUB USPAT;	2001/08/03 17:00
6	2772	(P\$3polysilicon ("P" adj8 polysilicon))	US-PGPUB USPAT;	2001/08/03 17:01
7	433	((P\$2substrat\$3 ("P" adj3 tupe adj2	US-PGPUB USPAT;	2001/08/03 16:19
		substrate))) and ((P\$2source ("P" adj7 source)))	US-PGPUB	
8	175	(((P\$2substrat\$3 ("P" adj3 tupe adj2 substrate))) and ((P\$2source ("P" adj7 source)))) and (gate adj3 electrode)	USPAT; US-PGPUB	2001/08/03 16:19
9	37	(((((P\$2substrat\$3 ("P" adj3 tupe adj2 substrate))) and ((P\$2source ("P" adj7 source)))) and (gate adj3 electrode)) and	USPAT; US-PGPUB	2001/08/03 16:23
10	400245	((P\$3polysilicon ("P" adj8 polysilicon))) substrate wafer	USPAT; US-PGPUB	2001/08/03 17:01
11	161409	(substrate wafer) and (dielectric insulat\$3 (silicon adj2 oxide))	USPAT; US-PGPUB	2001/08/03 17:02
12	57134	((substrate wafer) and (dielectric insulat\$3 (silicon adj2 oxide))) and (implant\$3 dop\$4)	USPAT; US-PGPUB	2001/08/03 17:02
13	14385	(((substrate wafer) and (dielectric insulat\$3 (silicon adj2 oxide))) and (implant\$3 dop\$4)) and epitaxial	USPAT; US-PGPUB	2001/08/03 17:02
14	11343	((((substrate wafer) and (dielectric insulat\$3 (silicon adj2 oxide))) and (implant\$3 dop\$4)) and epitaxial) and (boron "B")	USPAT; US-PGPUB	2001/08/03 17:03
15	10399	(((((substrate wafer) and (dielectric insulat\$3 (silicon adj2 oxide))) and (implant\$3 dop\$4)) and epitaxial) and (boron "B") and (phosphrous "P")	USPAT; US-PGPUB	2001/08/03 17:03
16	2833	((((((substrate wafer)) and (dielectric insulat\$3 (silicon adj2 oxide))) and (implant\$3 dop\$4)) and epitaxial) and (boron "B")) and (phosphrous "P")) and (P\$2channel\$2 ("P" adj2 channel) P?channel)	USPAT; US-PGPUB	2001/08/03 17:04
17	1381	<pre>((((((substrate wafer) and (dielectric insulat\$3 (silicon adj2 oxide))) and (implant\$3 dop\$4)) and epitaxial) and (boron "B")) and (phosphrous "P")) and (P\$2channel\$2 ("P" adj2 channel) P?channel)) and anneal\$3</pre>	USPAT; US-PGPUB	2001/08/03 16:36
18	351	(P\$2substrat\$3 ("P" adj3 tupe adj2 substrate))	EPO; JPO; DERWENT; IBM TDB	2001/08/03 17:00
19	7629	(P\$2source ("P" adj7 source))	EPO; JPO; DERWENT; IBM TDB	2001/08/03 17:00
20	73183	gate adj3 electrode	EPO; JPO; DERWENT; IBM TDB	2001/08/03 17:01
21	1220	(P\$3polysilicon ("P" adj8 polysilicon))	EPO; JPO; DERWENT; IBM TDB	2001/08/03 17:01
22	0	((P\$2substrat\$3 ("P" adj3 tupe adj2 substrate))) and ((P\$2source ("P" adj7 source))) and (gate adj3 electrode) and	EPO; JPO; DERWENT; IBM TDB	2001/08/03 17:01
23	9	((P\$3polysilicon ("P" adj8 polysilicon))) ((P\$2substrat\$3 ("P" adj3 tupe adj2 substrate))) and ((P\$2source ("P" adj7	EPO; JPO; DERWENT;	2001/08/03 17:01
24	1094018	source))) and (gate adj3 electrode) substrate wafer	IBM TDB EPO; JPO; DERWENT;	2001/08/03 17:02
			IBM TDB	



25	236460	(substrate wafer) and (dielectric	EPO; JPO;	2001/08/03 17:02
		insulat\$3 (silicon adj2 oxide))	DERWENT;	ĺ
			IBM TDB	
26	26997	, , , , , , , , , , , , , , , , , , , ,	EPO; JPO;	2001/08/03 17:02
		insulat\$3 (silicon adj2 oxide))) and	DERWENT;	
		(implant\$3 dop\$4)	IBM TDB	
27	2563	, , , = ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ===== , ======	EPO; JPO;	2001/08/03 17:03
		insulat\$3 (silicon adj2 oxide))) and	DERWENT;	
		(implant\$3 dop\$4)) and epitaxial	IBM TDB	
28	1341	((((EPO; JPO;	2001/08/03 17:03
		insulat\$3 (silicon adj2 oxide))) and	DERWENT;	j
		(implant\$3 dop\$4)) and epitaxial) and	IBM TDB	
00	0.40	(boron "B")		
29	849	(((((((((((((((((((((((((((((((((((((((EPO; JPO;	2001/08/03 17:03
		insulat\$3 (silicon adj2 oxide))) and	DERWENT;	
		(implant\$3 dop\$4)) and epitaxial) and	IBM TDB	·
30	56	(boron "B")) and (phosphrous "P")	770	0001/00/00 15 01
30	36	(((((((((((((((((((((((((((((((((((((((EPO; JPO;	2001/08/03 17:04
		insulat\$3 (silicon adj2 oxide))) and	DERWENT;	
		(implant\$3 dop\$4)) and epitaxial) and	IBM TDB	
		(boron "B")) and (phosphrous "P")) and		
		(P\$2channel\$2 ("P" adj2 channel) P?channel)		
		r:Channel)		